

Sources d'ions et accélérateurs

le programme de développement au SSI

Résumé

Une fois démarrés, les accélérateurs d'ions, que ce soit des cyclotrons, des synchrotrons ou même de simple plate-forme haute tension, peuvent voir leurs performances décuplées uniquement par l'introduction de nouvelles sources d'ions. C'est ceci qui est à l'origine du dynamisme et de l'intérêt pour le développement de nouvelles machines.

Le Service des Sources d'Ions étant principalement engagé dans la mise au point de sources d'ions lourds (masse supérieure à celle de l'hydrogène), nous rappellerons les principaux procédés de production des ions et tout particulièrement les principes de base des sources de types ECR (pour Electron Cyclotron Resonance).

Nous nous efforcerons de montrer en quoi la mise au point des systèmes d'augmentation en charge des faisceaux (Charge breeding) initialement développé pour le projet PIAFE permettent l'amélioration de presque tous les projets d'accélération en ligne des faisceaux secondaires. Nous mettrons aussi en lien les différents schémas d'injection des ions lourds au CERN avec les différentes approches concernant la production de faisceaux pulsés d'ions Pb.

Sources d'ions et accélérateurs

le programme de développement au SSI

1. **Introduction** : *Sources d'ions et accélérateurs*
2. **Les sources ECR** : *les principes*
3. **Sources ECR et faisceaux secondaires** : *production en ligne et charge breeding*
4. **Sources ECR et synchrotrons** : *optimisation faisceaux pulsés / continus*
5. **Prospectives** : *PHOENIX “Booster 18 GHz”
A-PHOENIX HTS 28 – 40 GHz*

Sources d'ions et accélérateurs

Ion : « non - neutral atom »

positive ions
negative ions
light ions
heavy ions
multicharged ions

Source : flux of ions

continuous
pulsed
low current
high current
high brightness
low brightness
efficiency

ION BEAMS

An **energy**, generally per mass unit

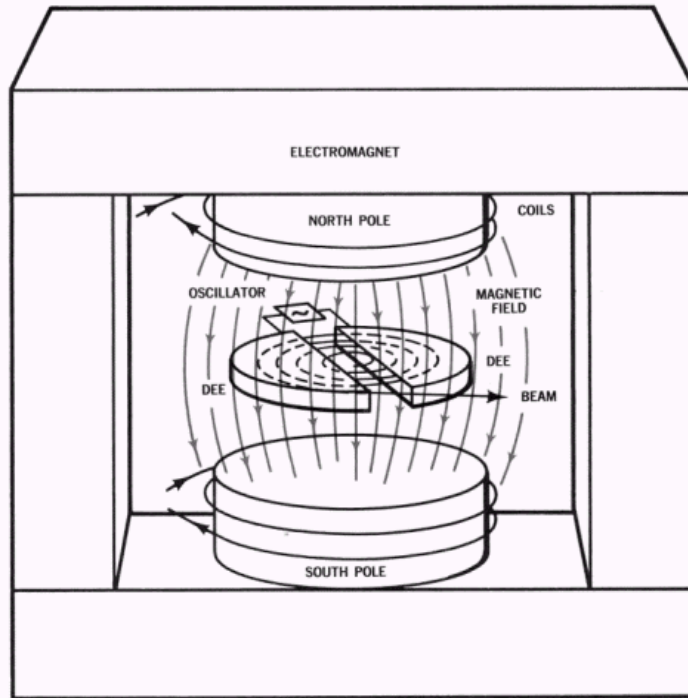
An **intensity**, generally particules/second

A **transversal emittance**, generally the intrinsic transversal energy spread and the size of the beam

A **longitudinal emittance**, generally the intrinsic longitudinal energy spread and the time structure

Sources d'ions et accélérateurs

Sources d'ions et cyclotrons



The cyclotron is characterised by the parameter K defined by

$$W_n^{\max} = K \left(\frac{q}{A} \right)^2$$

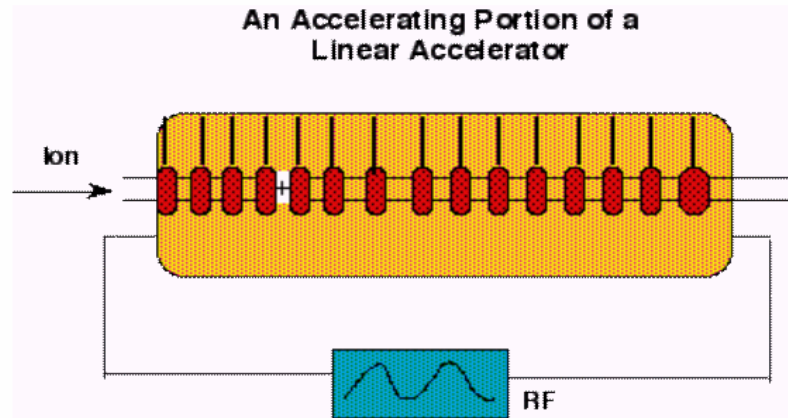
where W_n^{\max} is the maximum energy per nucleon achievable, q the number of charge of the ion and A the number of mass of the ions.

The expression of K is : $K = \frac{R^2 B_{\max}^2}{2m_n}$ where B_{\max} is the maximal induction, R the mean radius of the extraction trajectory et m_n the mass of the nucleon

Ex. : “88 inch” Berkeley cyclotron, 40 years old, accelerate Bi^{46+} up to 6 Mev/uma.

Sources d'ions et accélérateurs

Sources d'ions et accélérateurs linéaires

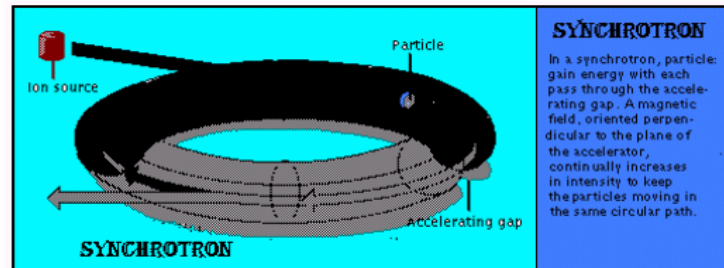


For a linear accelerator, the energy is $W_n^{\max} \propto (q/A)$ where W_n^{\max} is the maximum energy per nucleon achievable, so the number of accelerator gap, so the length of the machine , so the price!

Synchrotron are fundamentally cyclic accelerator , a bunch of particule is injected, followed by the accelerating time.

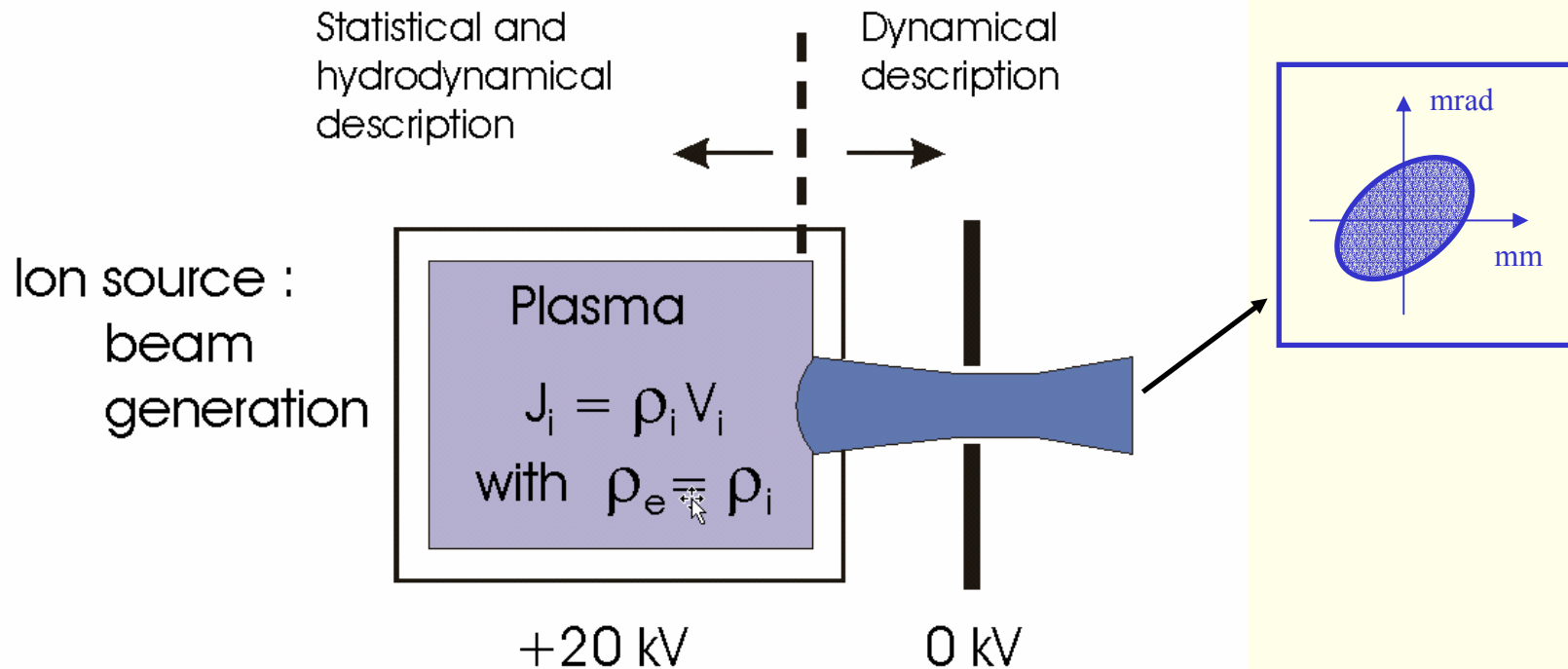
So the ion source must deliver a pulsed beam with a miximum intensity during some μs every second !

I≡



Sources d'ions et accélérateurs : *plasma and ion beam generation*

A plasma is called quasineutral if the number of positive charges per unit volume equals the negative charge density



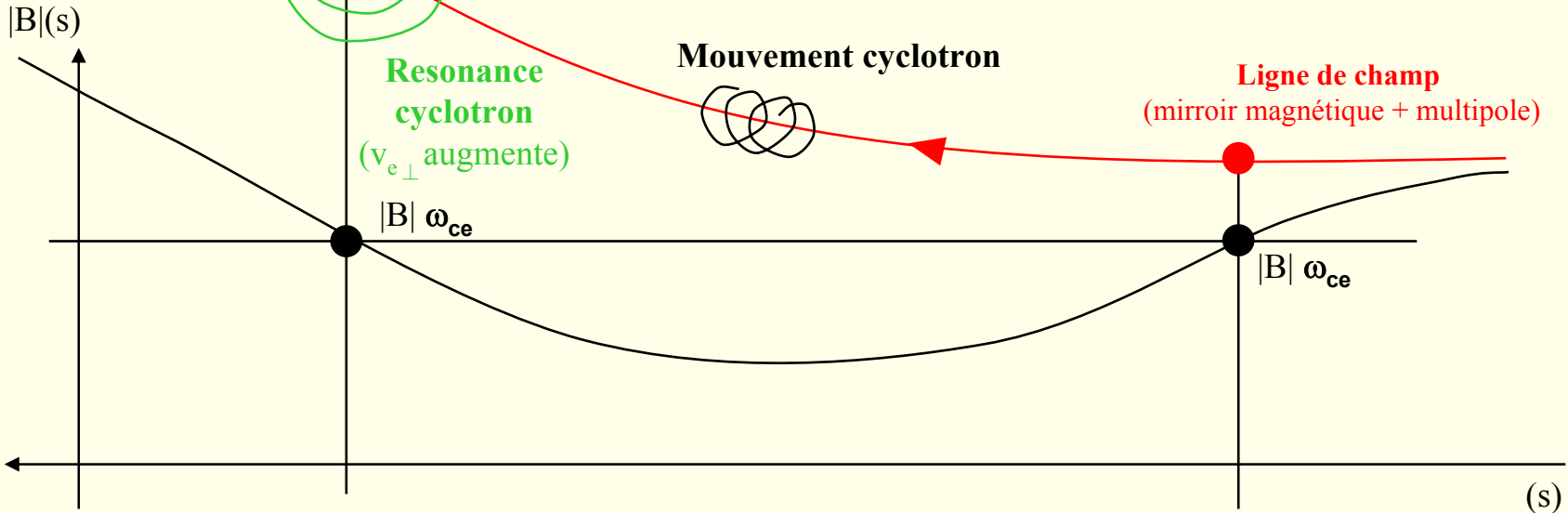
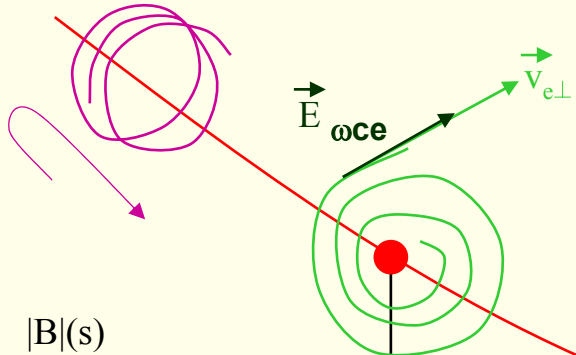
The ion current is determined only by ion temperature, ion density and area of extraction opening

Résonance cyclotronique électronique: ω_{ce}

Les mouvements de l'électron : mouvement cyclotron simple
 mouvement cyclotron dans le gradient (miroir magnétique)

- résonance cyclotron simple (passage unique)*
- résonance cyclotron multiple (stochastique)*
- collision e-e (diffusion élastique)*
- collision i-e (équilibre thermique et collisions ionisantes)*
- équilibre macroscopique du plasma ($n_e n_i T_e T_i$)*
- propagation de l'onde UHF (14 GHz) (fréquence de coupure)*
- champ électrique utile au niveau de la résonance*

Effet miroir ($v_{||} = 0, v_{\perp} \text{max}$)



Multicharged ion production : *Ionization equilibrium*

Balance equation of the density n_i of ions in the charge state i :

$$\frac{\partial n_i}{\partial t} = \sum_{j_{\min}}^{i-1} n_e n_j \langle \sigma_{j \rightarrow i}^{ioni} v_e \rangle + n_o n_{i+1} \langle \sigma_{i+1 \rightarrow i}^{exc} v_i \rangle - n_o n_i \langle \sigma_{i \rightarrow i+1}^{exc} v_i \rangle - \sum_{j=i+1}^{j_{\max}} n_e n_j \langle \sigma_{j \rightarrow i}^{ioni} v_e \rangle - \frac{n_i}{\tau_i}$$

Parametric model with n_e , $f(v_e)$, τ_i and n_0 arbitrary

n_e : electronic density

$f(v_e)$: electronic speed distribution

τ_i : ionic diffusion time

n_0 : neutral density

with $\tau_i = K_{diff} z_i^2$ (or more sophisticated description of ionic plasma diffusion process)

ionisation cross section:

$$\sigma_i^{ioni} = A_i^{ioni} \log(E_e / E_i^{ioni}) / E_i^{ioni} E_e$$

charge exchange cross section:

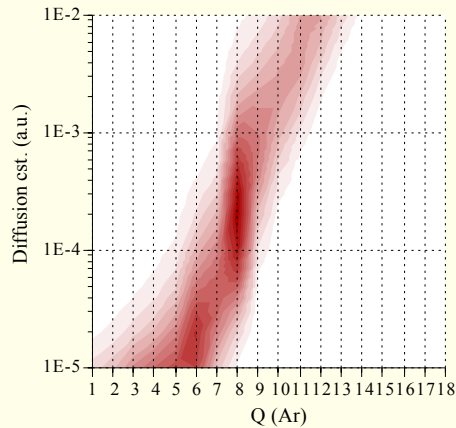
$$\sigma_{i,j-1}^{exc} = A^{exc} i / (E_0^{ioni})^3$$

with : A_i^{ioni} : ionisation constant

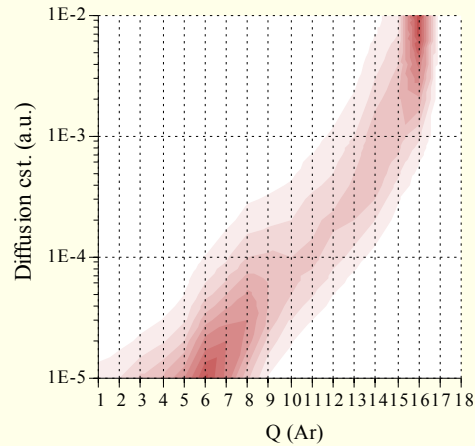
E_i^{ioni} : ionisation potential of state i

E_e : electronic energy

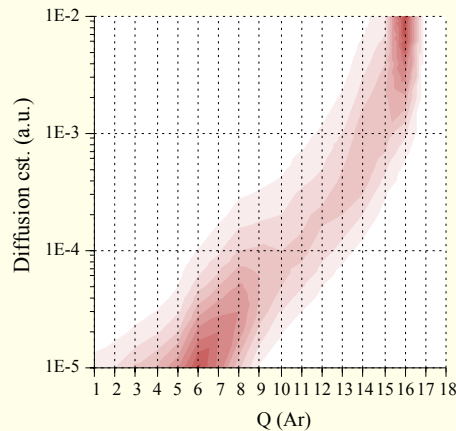
Multicharged ion production : *ionization equilibrium*



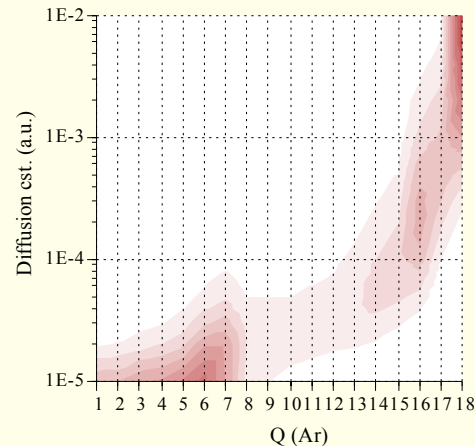
$T_e = 100$ eV (maxwellian)



$T_e = 300$ eV (maxwellian)



$T_e = 1000$ eV (maxwellian)



$T_e = 10000$ eV (maxwellian)

7E+10 6E+10 5E+10 4E+10 3E+10 2E+10 1E+10 0E+0



Density (cm⁻³) charge state distribution of Argon as a function of the confinement time of ions and for maxwellian distribution of electronic energy

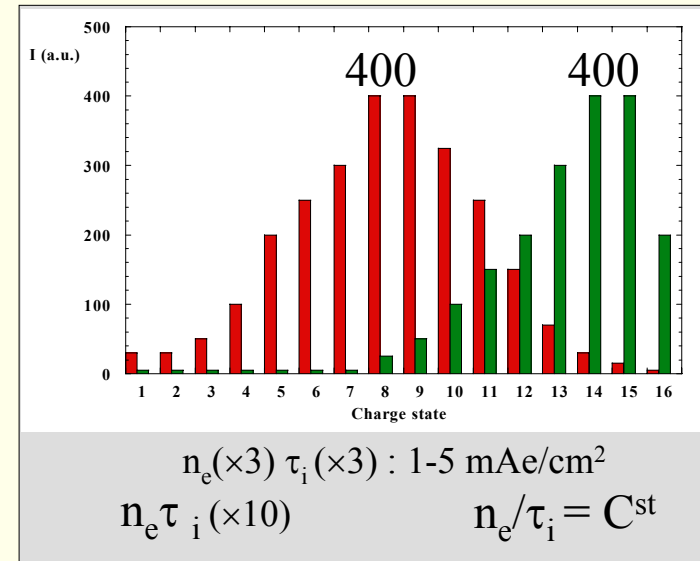
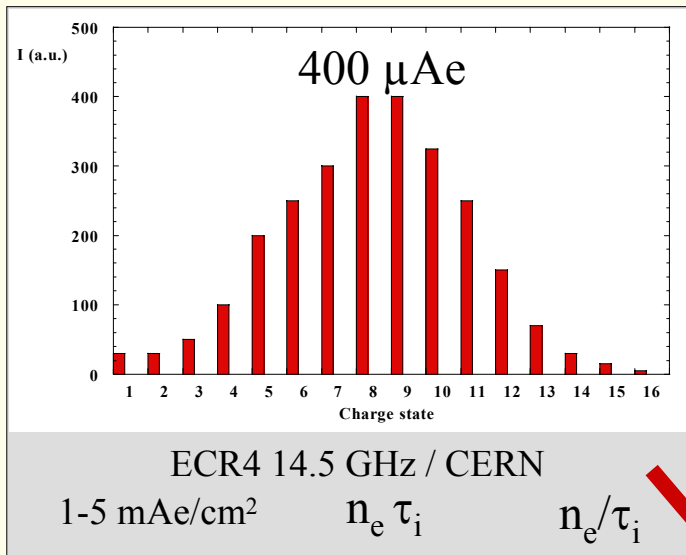
Ionisation Potential

Ar⁰ ≈ 15 eV Ar⁷⁺ ≈ 140 eV
 Ar⁸⁺ ≈ 450 eV Ar¹⁵⁺ ≈ 1000 eV
 Ar¹⁶⁺ ≈ 4400 eV

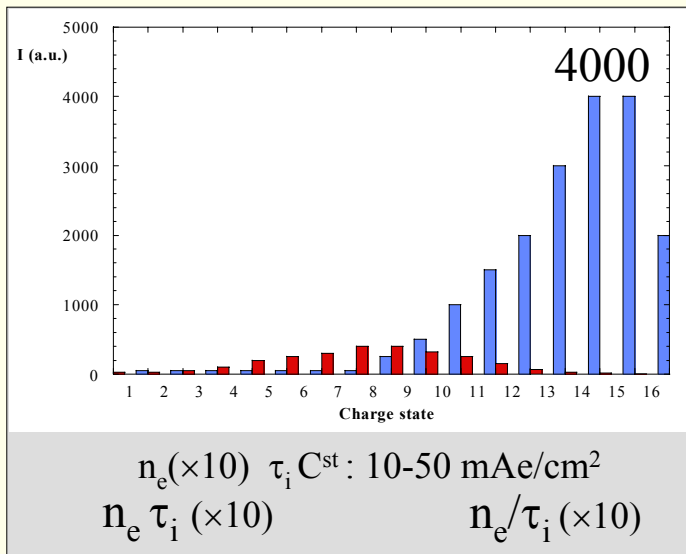
High current / high charge state optimization

$$J_i \propto n_e / \tau_i$$

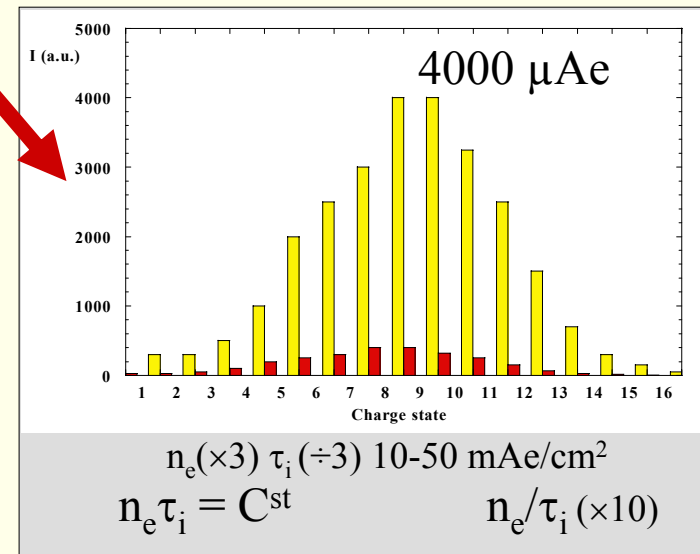
$$\langle Z \rangle \propto n_e \tau_i$$



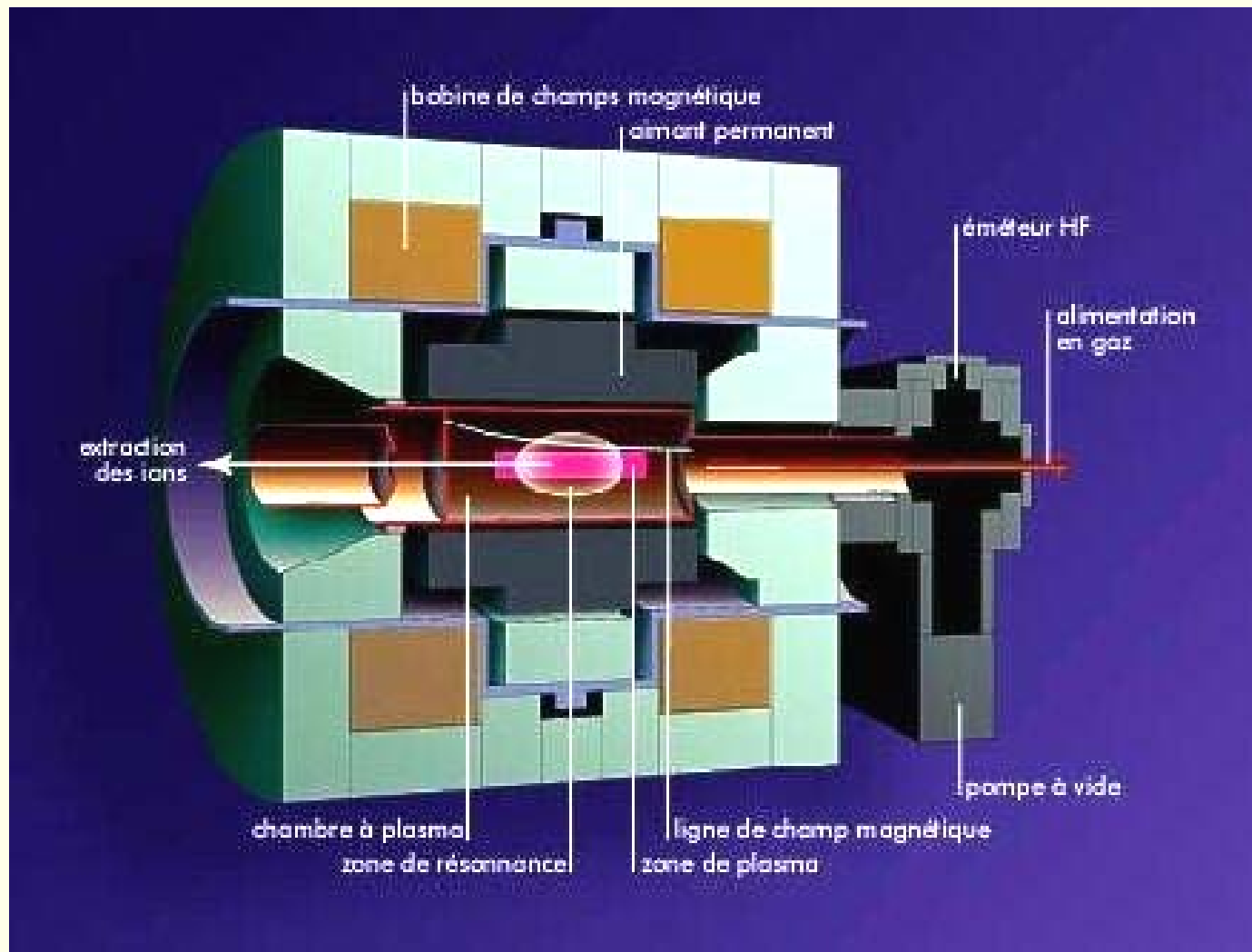
?



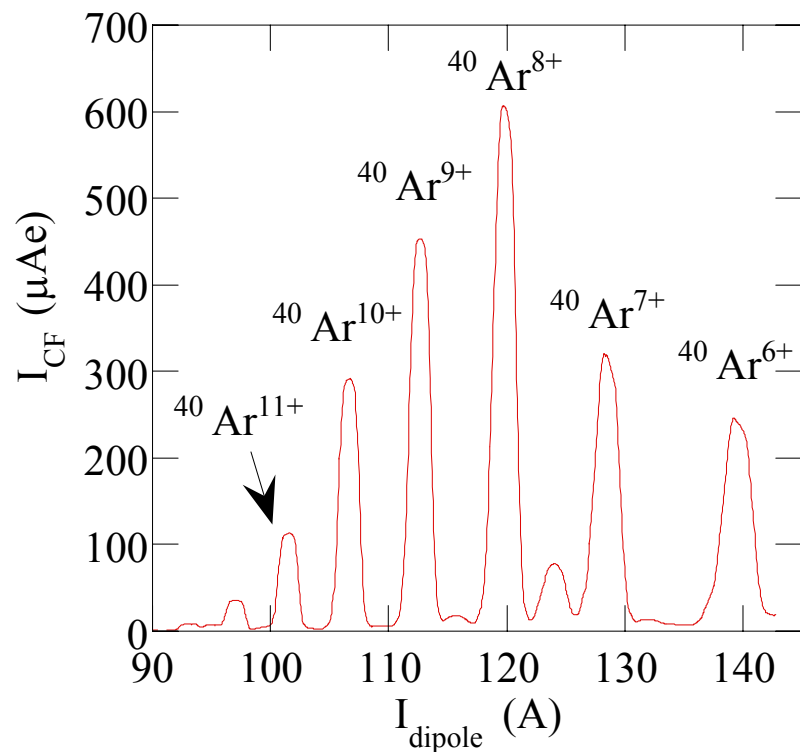
J_i
 P_{UHF}



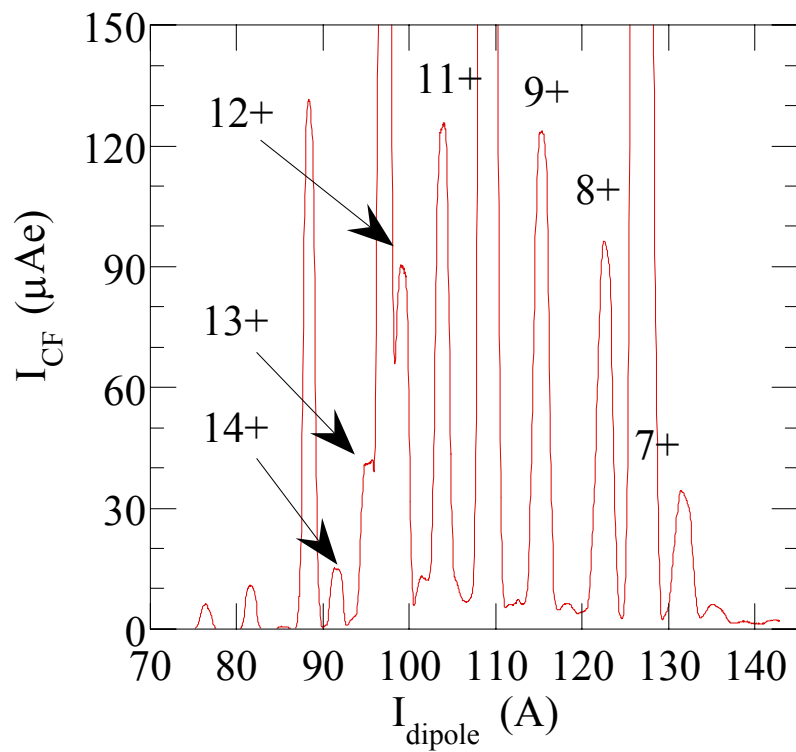
Electron Cyclotron Resonance Ion Source



Electron Cyclotron Resonance Ion Source : typical spectrum



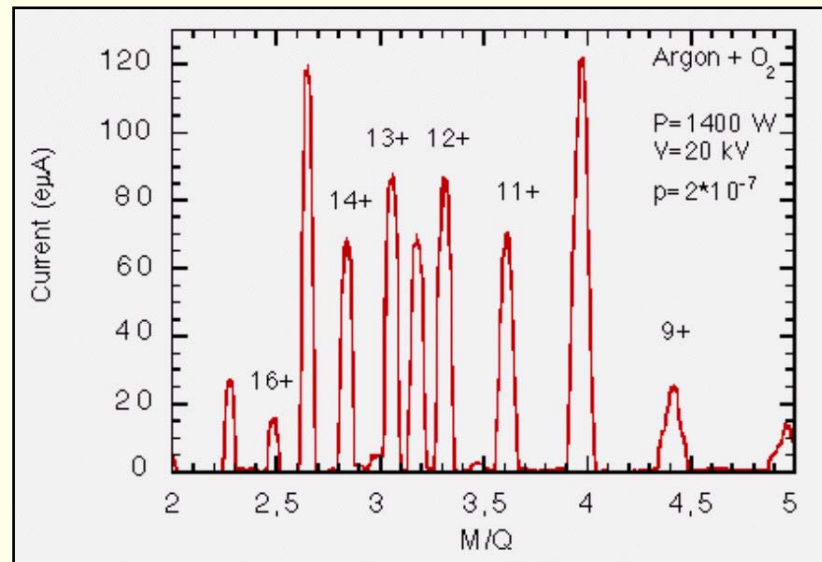
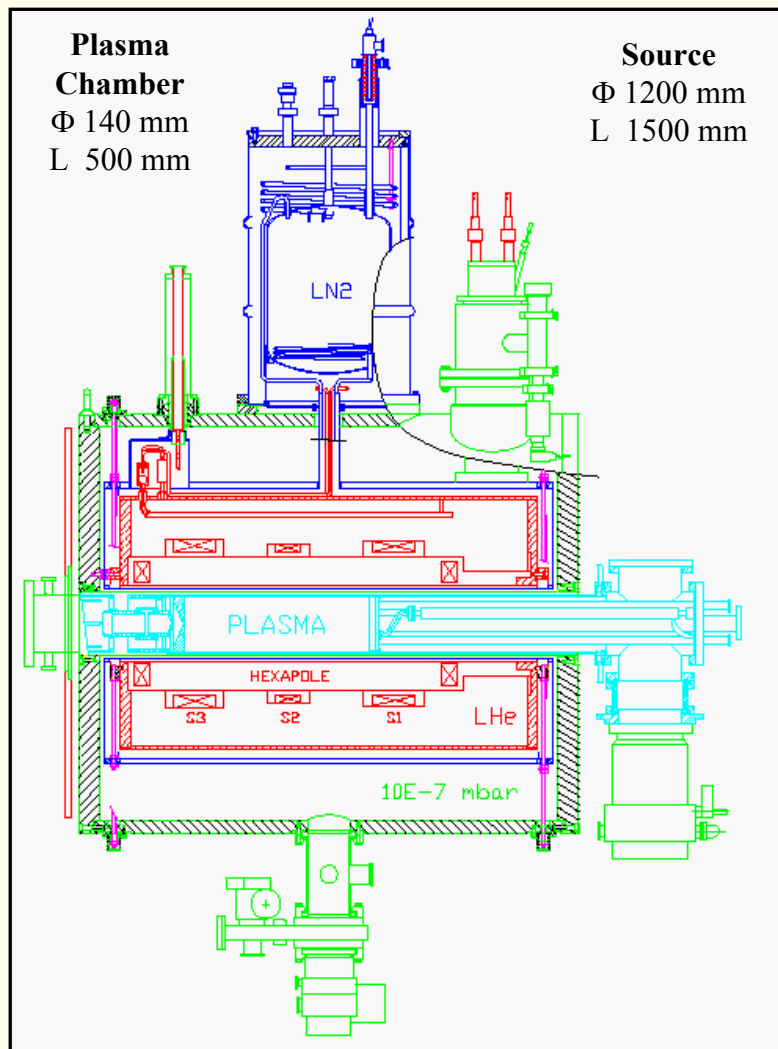
Ar $^{8+}$ tuning



Ar $^{14+}$ tuning

ECR4-M 14.5 GHz / GANIL / 25 KV

Electron Cyclotron Resonance Ion Source : *Source supraconductrice CENG/LNS Catane*



Pour :

> sources compactes sur très fortes charges Ar > 14+

Contre :

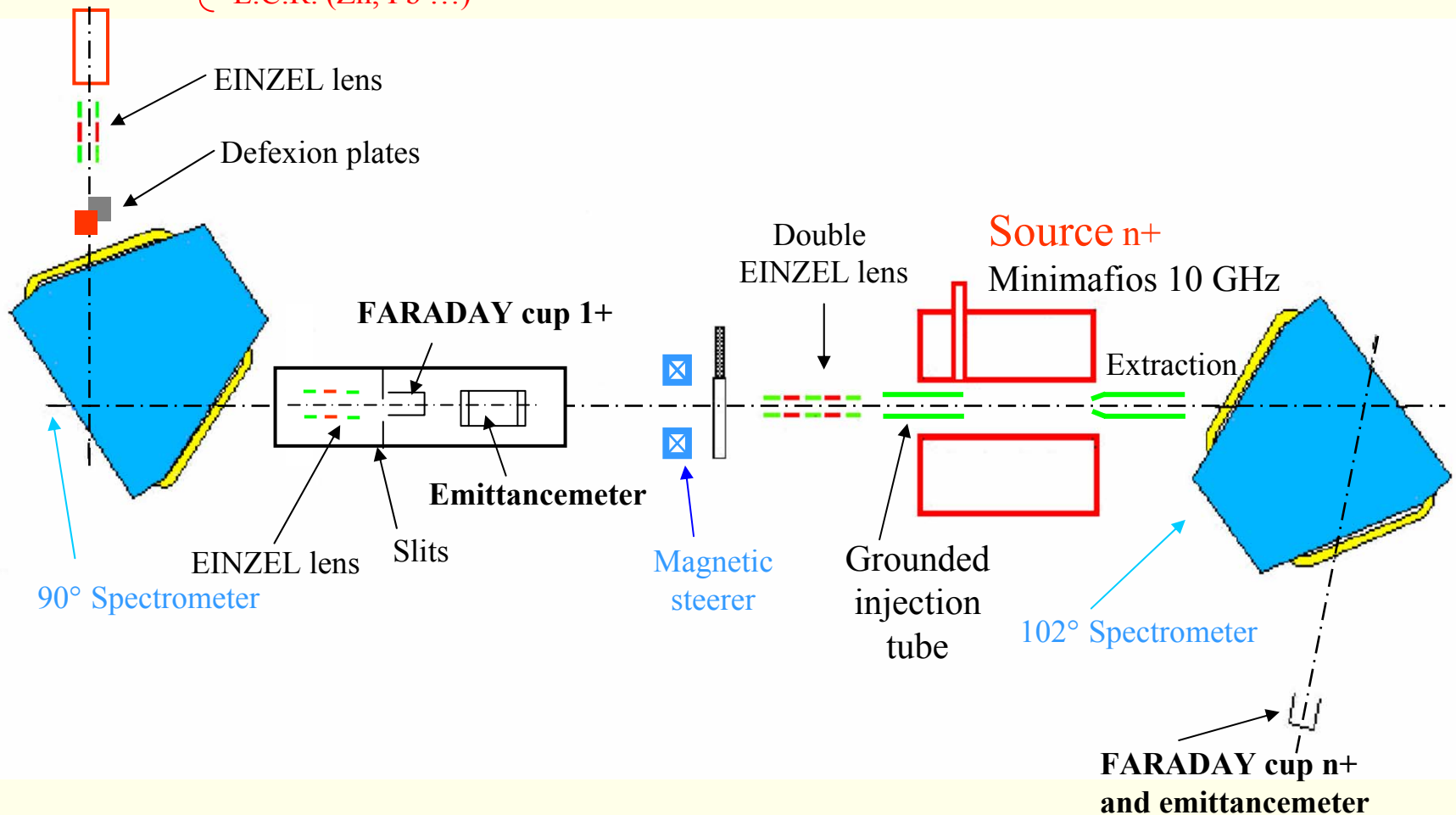
< sources compactes sur charges moyennes ou faibles Ar < 14+

Compromis fort courant ?

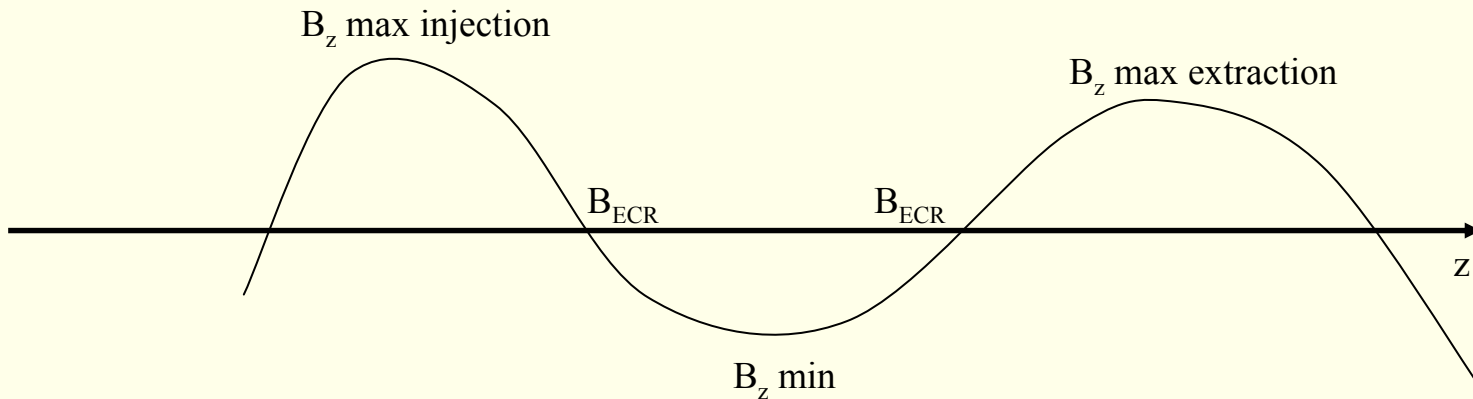
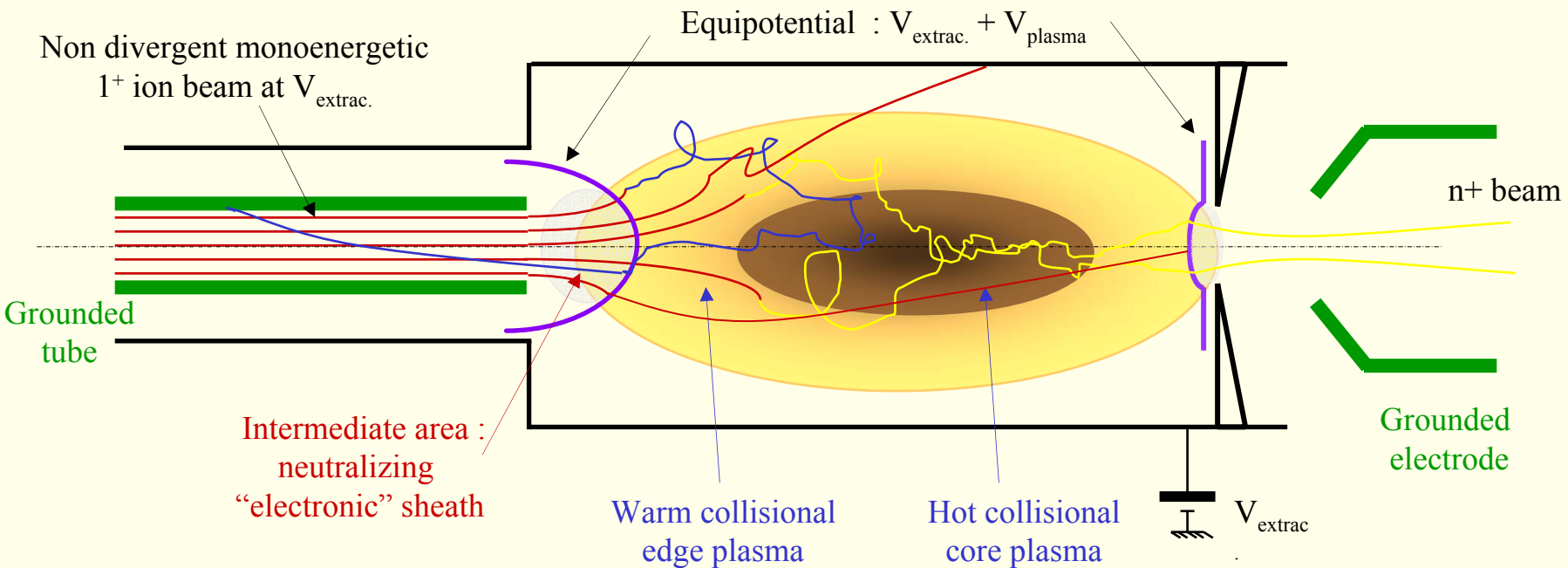
Coût environ 10 fois supérieure

Experimental setup for the $1+/n+$ charge breeding

- $1+$ Source
- Thermoionic (Rb)
 - Hollow Cathode (Zn)
 - E.C.R. (Zn, Pb ...)



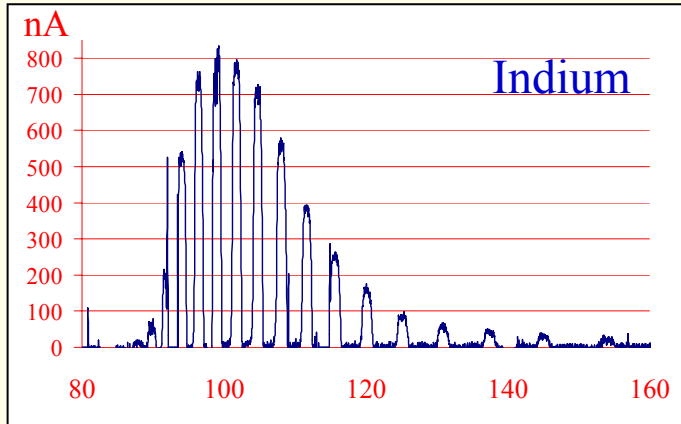
1+ / n+ transformation with an ECRIS for multicharged ions



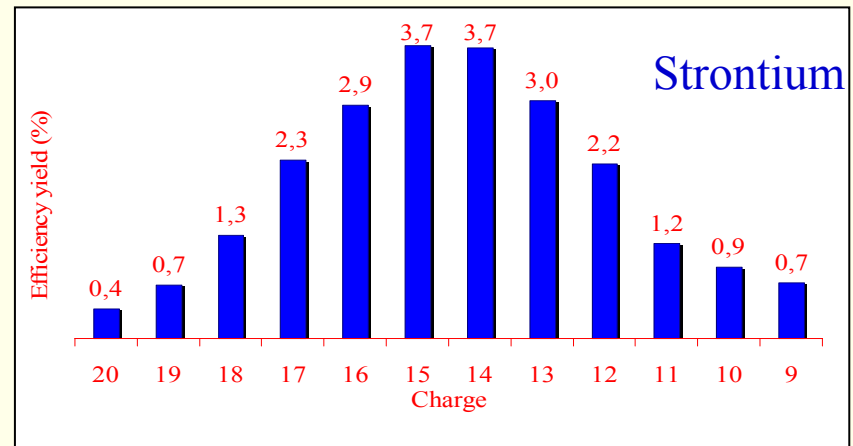
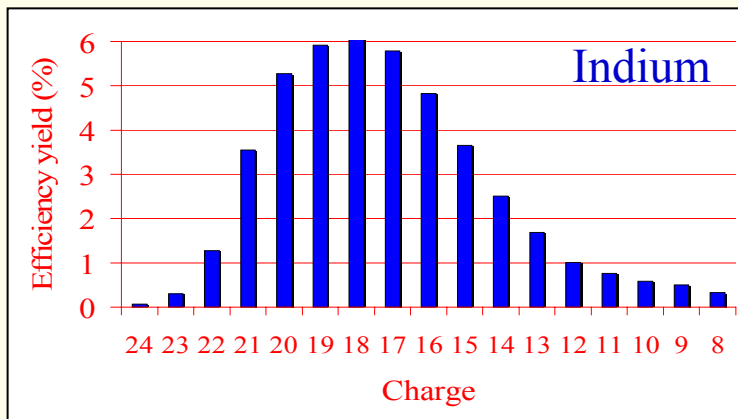
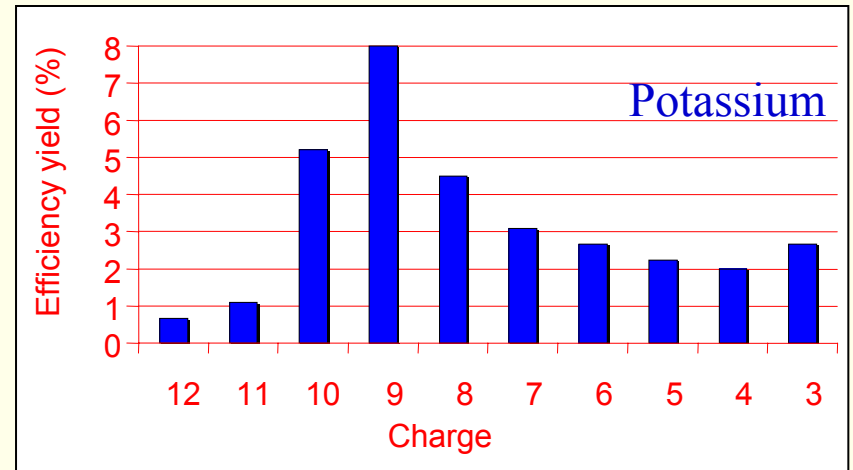
Experimental setup for the 1+/n+ charge breeding

Efficiency yields

Delta I measurement



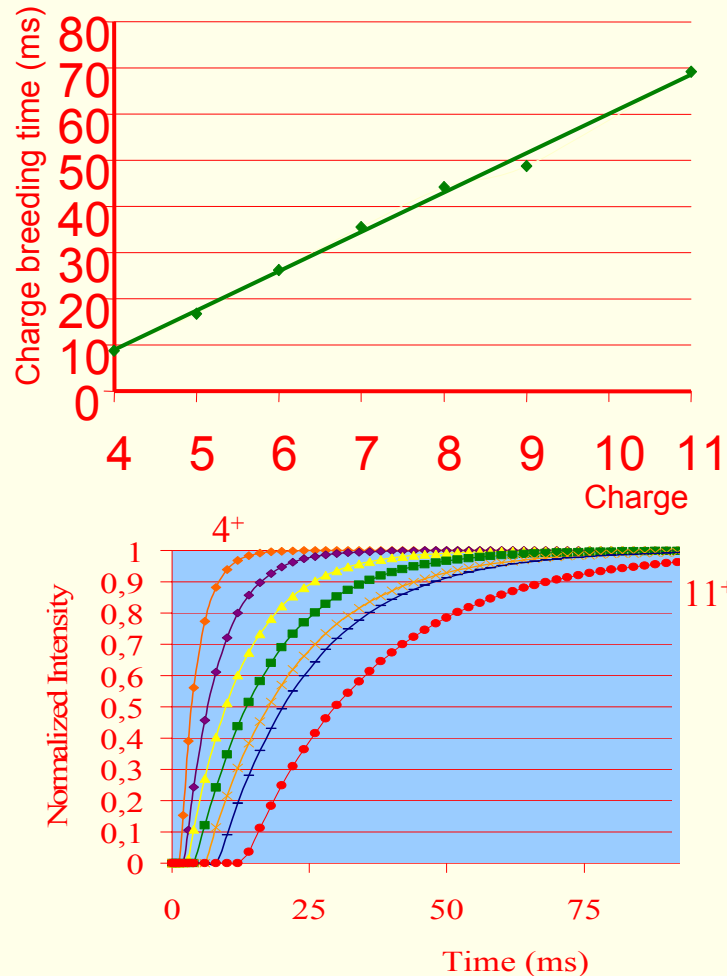
I Spectrometer



CSD efficiency yield

Experimental result with the 1+/n+ charge breeding

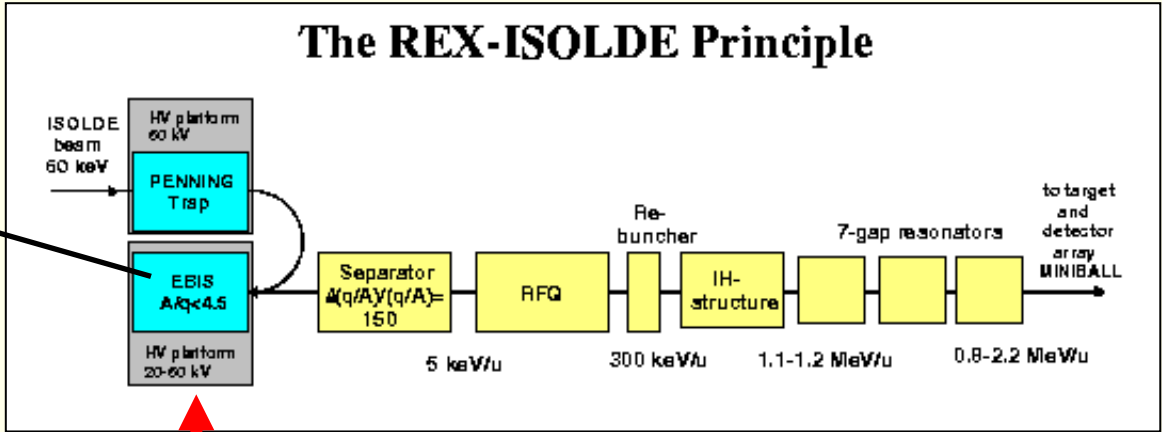
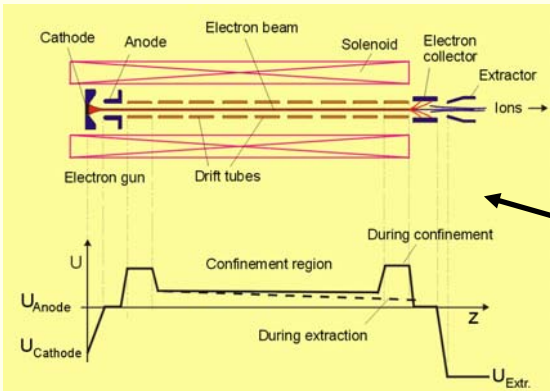
Charge breeding time τ_{cbt} with ^{39}K



Produced elements

Element	1+ Intensity (nA)	n+ Charg	Yield (%)
^{20}Ne	1000	4	7.5
^{23}Na	660	6	1.3
^{39}K	280	6	6.5
^{64}Zn	42	10	2.8
^{69}Ga	460	11	2
^{85}Rb	90	13	5
^{88}Sr	470	14	3.7
^{90}Y	178	14	3.3
^{109}Ag	175	17	3
^{115}In	130	18	3.3
^{120}Sn	167	19	4.1
^{208}Pb	700 (2+)	25	6.8

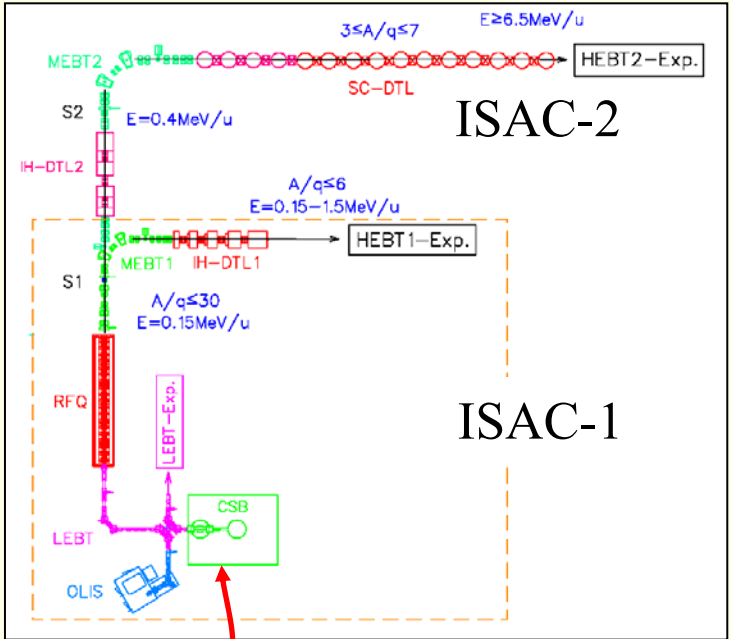
The EBIS charge breeder/stripper versus the ECRIS one



Phoenix 14 GHz
« Daresbury »

Fabriquées par Pantechnik
sous contrat ISN/Pantechnik (CROP)

Phoenix 14 GHz
Triumpf



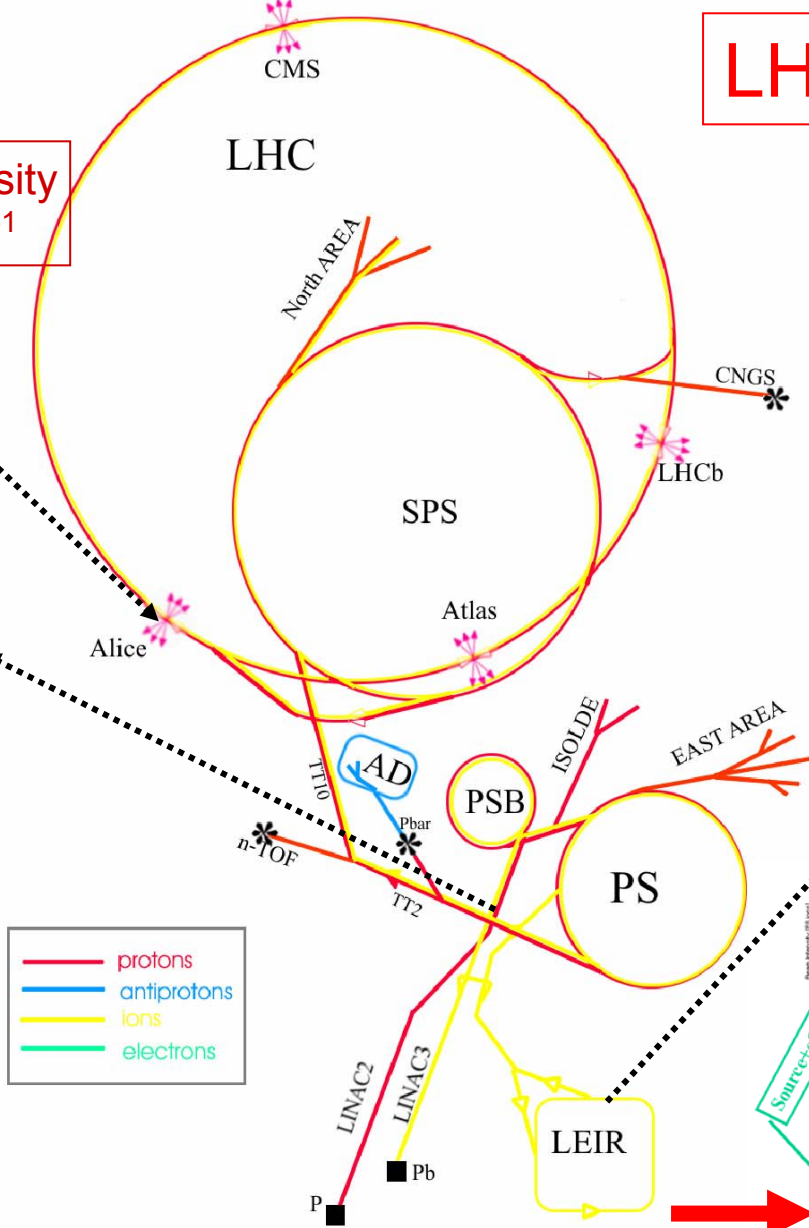
LHC Pb and ion source

LHC Pb luminosity
 $7 \cdot 10^{27} \text{ cm}^{-2} \text{ s}^{-1}$

Voie directe
 vers le booster

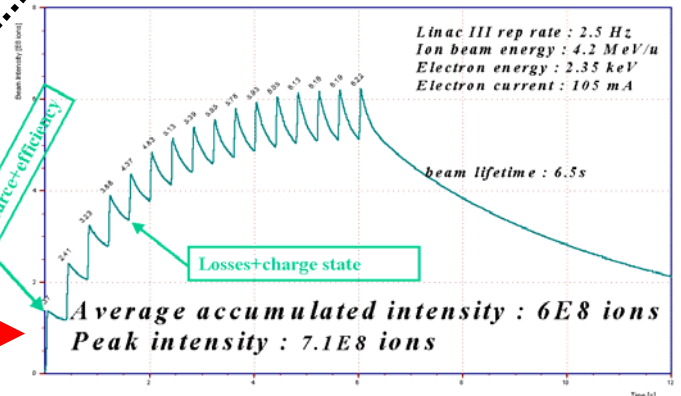
6 mA
 5.5 μs
 $\sim 10^8$ ions/bunch

Voie d'accumulation
 dans LEIR

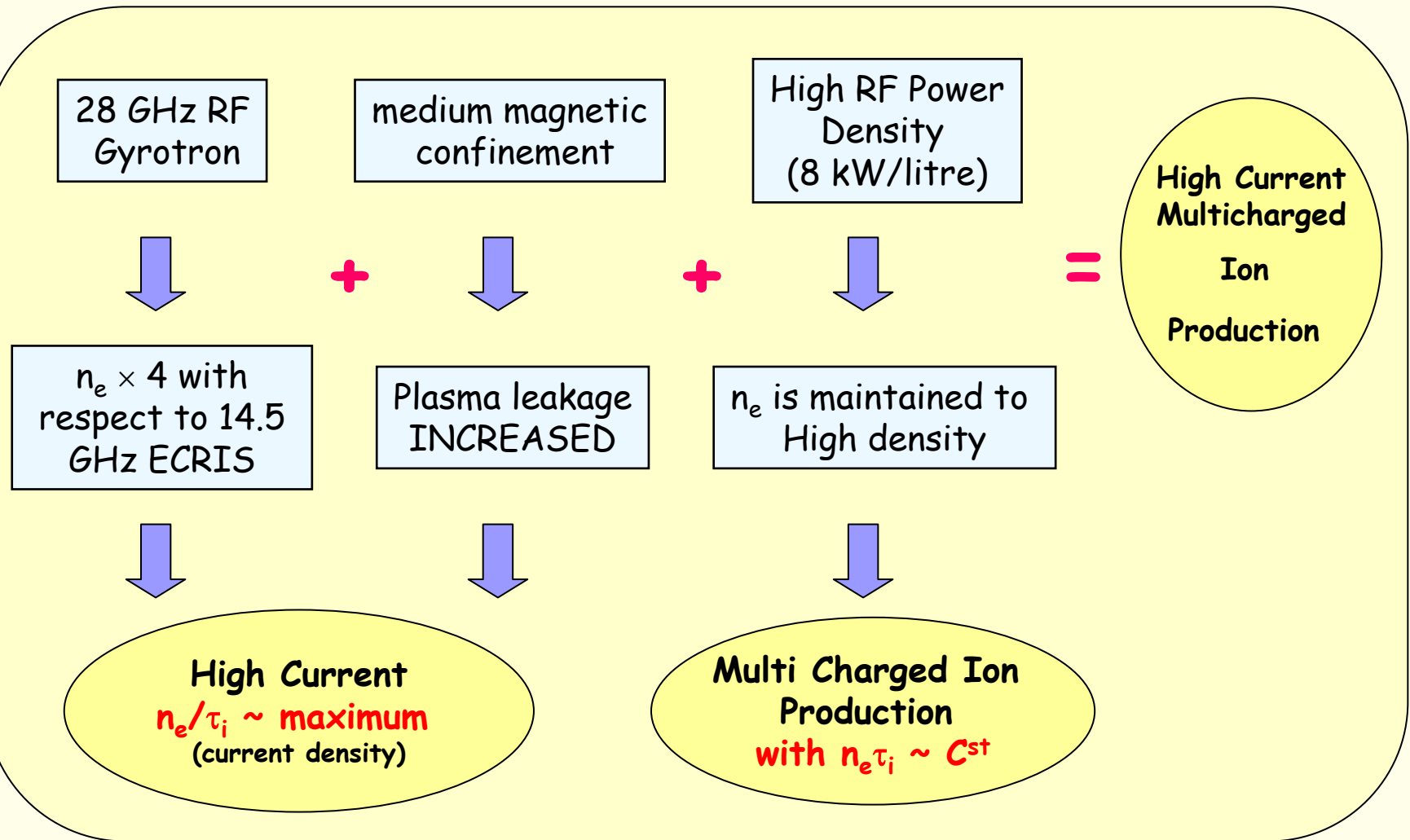


- protons
- antiprotons
- ions
- electrons

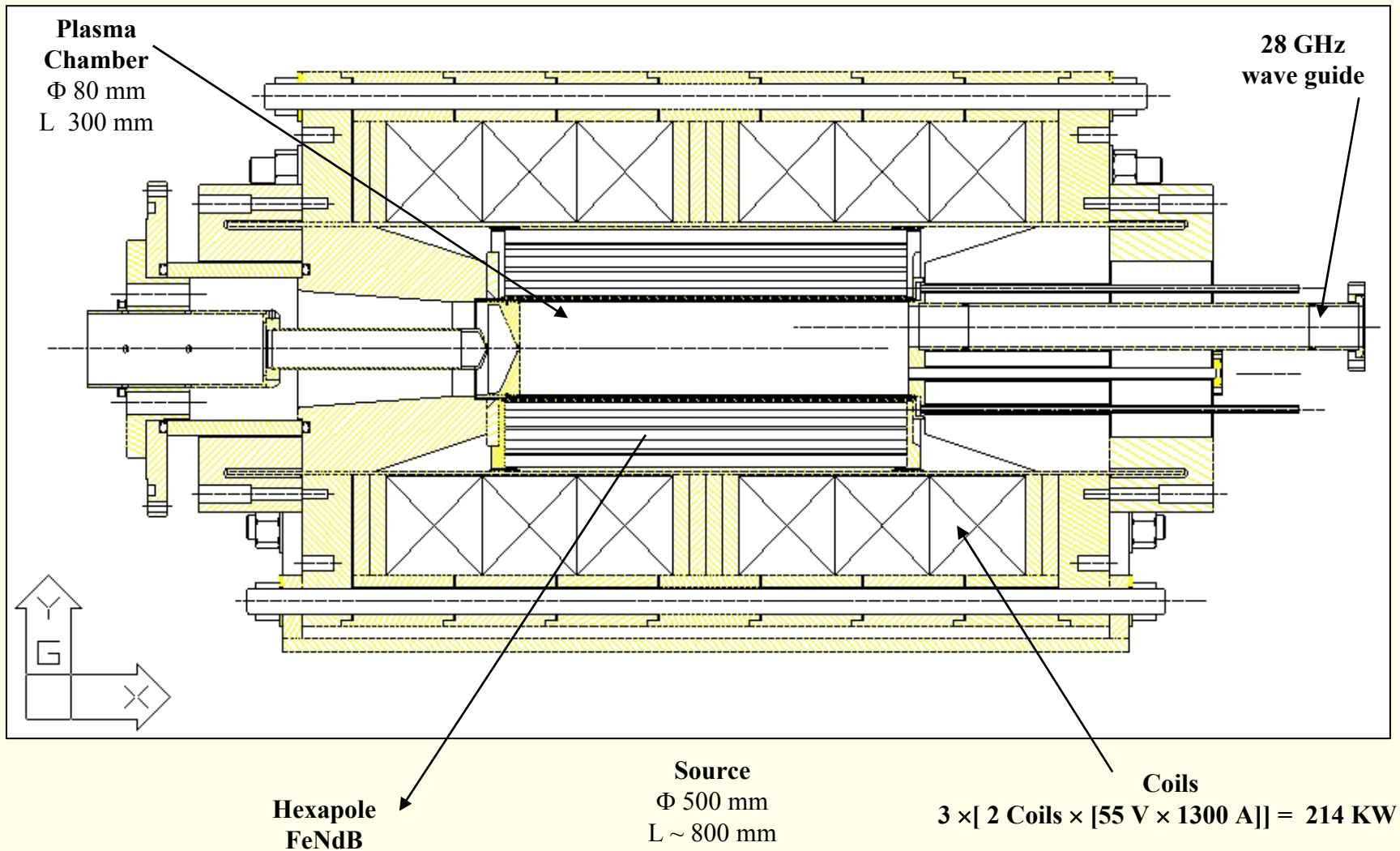
0.25 mA / 450 μs



PHOENIX strategy to produce High Multi Charged Ion beams



PHOENIX 28 GHz



PHOENIX 28 GHz : 60 KV high current beam line

Emittancemeter

Solenoid 2
Gap 90 mm

Bending
magnet
Gap 100 mm

Faraday Cup 1
Ø50 mm

PHOENIX
28 GHz / 60 KV

Faraday cup 2
Ø35 mm

Movable
Slits

Solenoid 1
Gap 100 mm

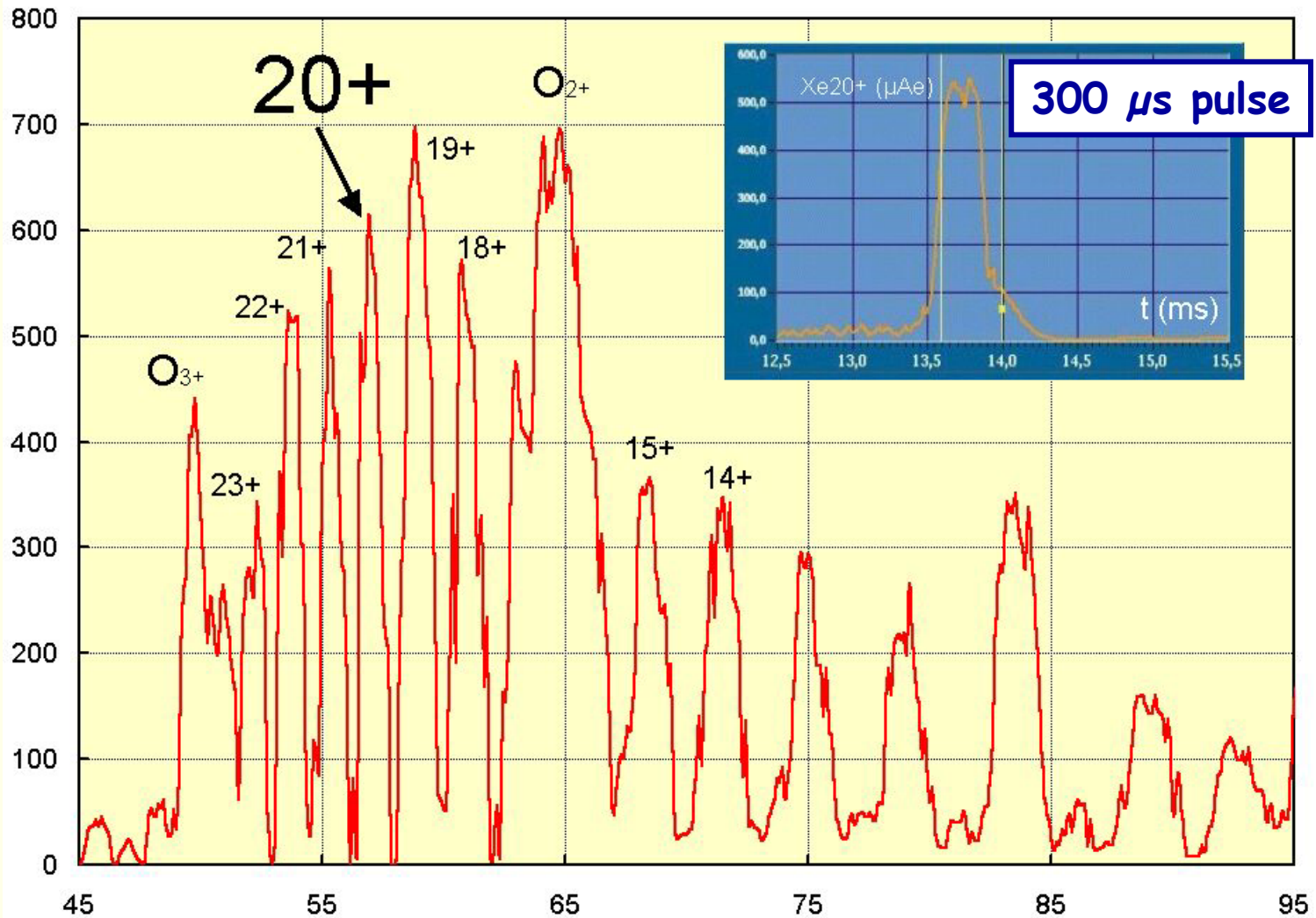
Movable
Puller

28 GHz
Gyrotron

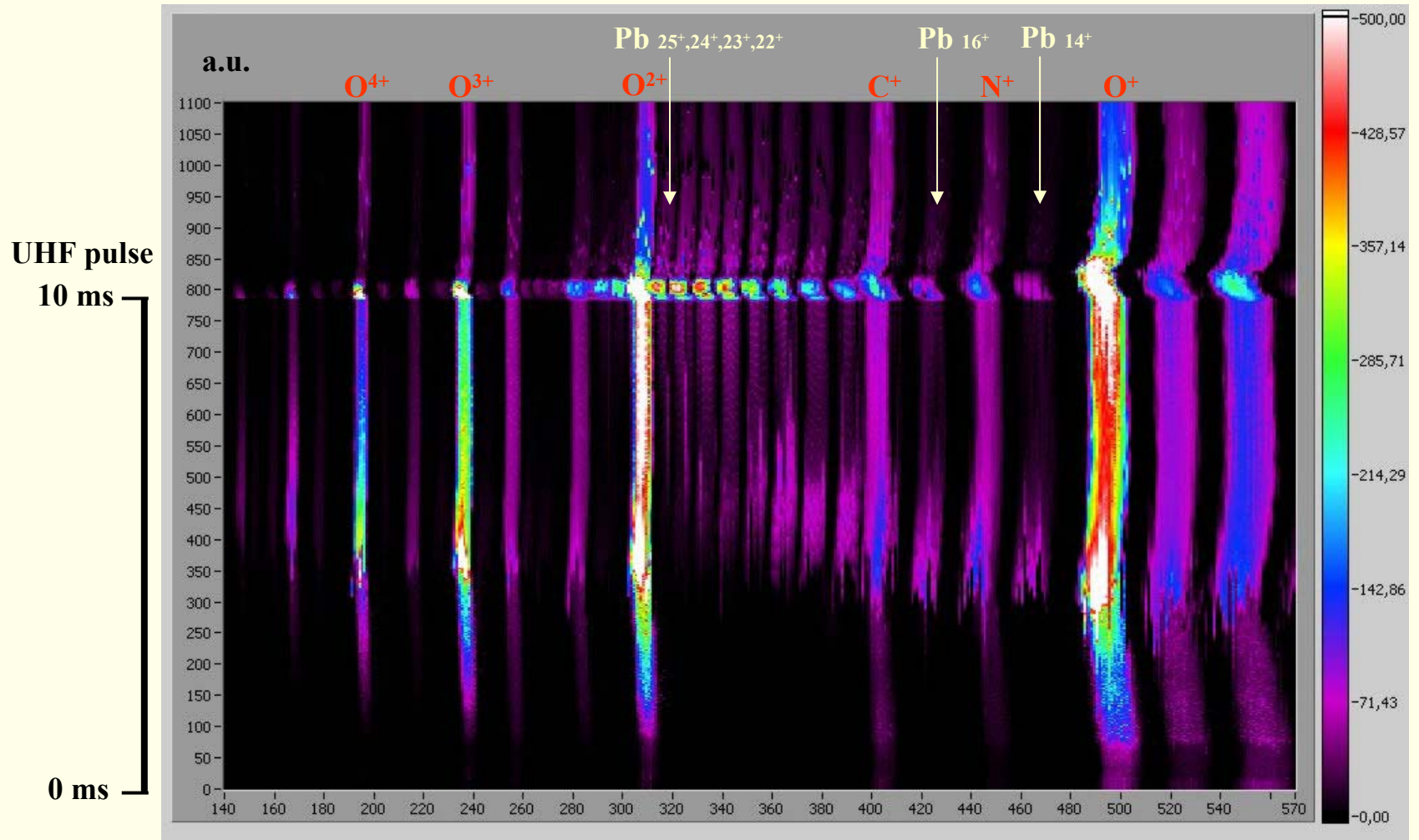
PHOENIX 28 GHz : afterglow control with Lead

$e\mu A$

➤ 55 KV
➤ \varnothing 12 mm
electrode

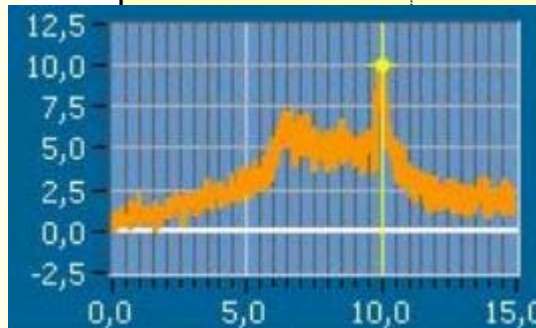


PHOENIX 28 GHz : afterglow control with Lead

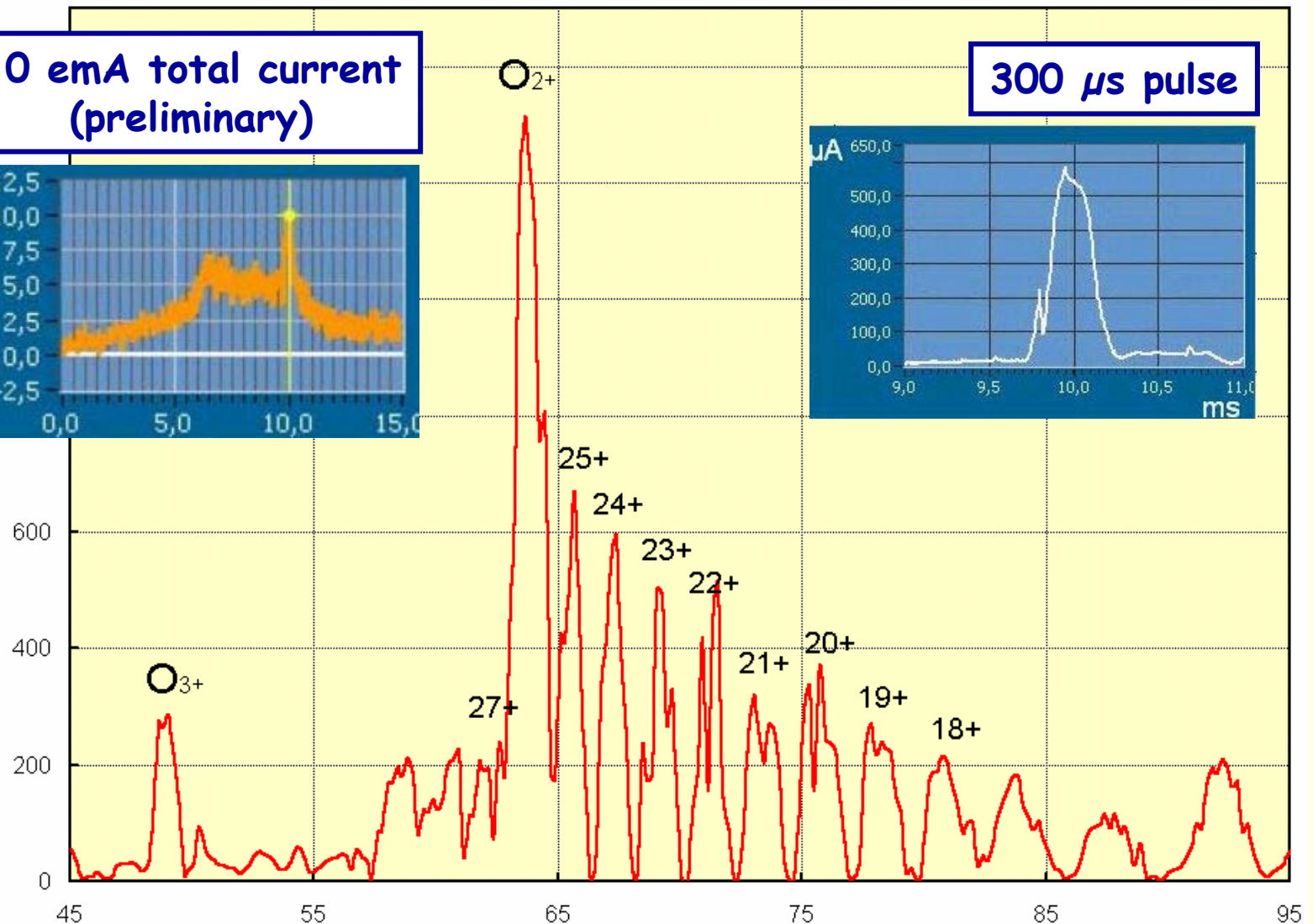
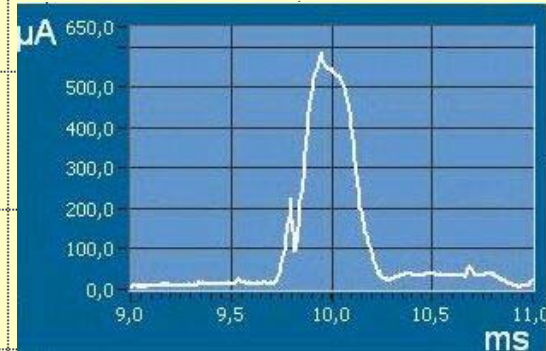


PHOENIX 28 GHz : high current extraction (Lead)

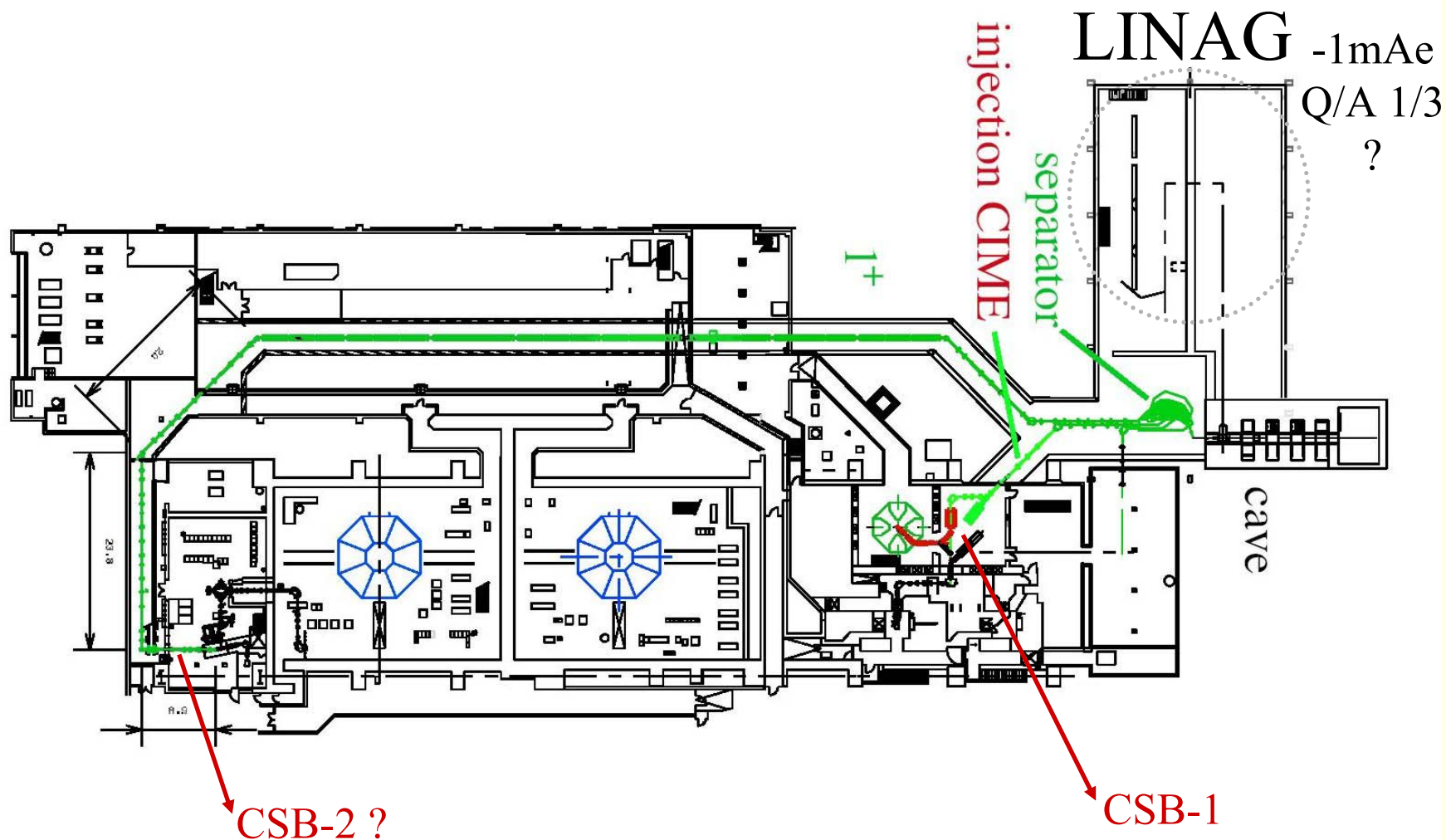
10 emA total current
(preliminary)



300 μ s pulse



Sources ECR et faisceaux secondaires



A-PHOENIX : 2T / 18-40 GHz HTS ECR source

A CW and pulsed compact ECRIS

- An upgraded version of the PHOENIX 28 GHz source
 1. *Very compact high field machine for high current production*
 2. *Development of a new coil technology for accelerator*
 3. *Upgrade of the UHF coupling efficiency*
 4. *Upgrade of the confinement for high current and/or high charge state optimization*
 5. *Higher B_r for lower UHF Power*
 6. *Higher $|B|$ for higher Z*
 7. *Multi frequency CW functioning at 18 and 28 GHz*
 8. *Pulsed operation at 40 GHz*
 9. *Possible application at CERN, GSI, GANIL/LINAG, INFN-LNL, HMI...*

A-PHOENIX : 2T / 18-40 GHz HTS source

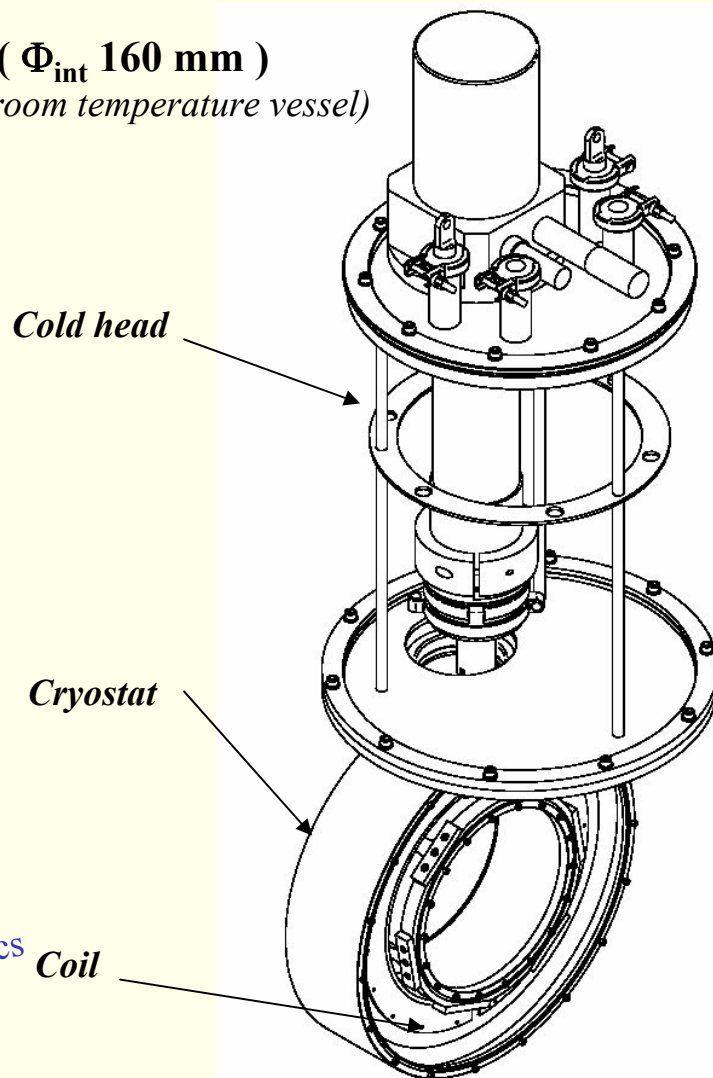
20 K compact multipurpose coil for accelerator application

New very compact 20 K cryostat (Φ_{int} 160 mm)
(down to 18 mm between the cold coil and the room temperature vessel)

Prototype coil (tested for 90 A/mm²)



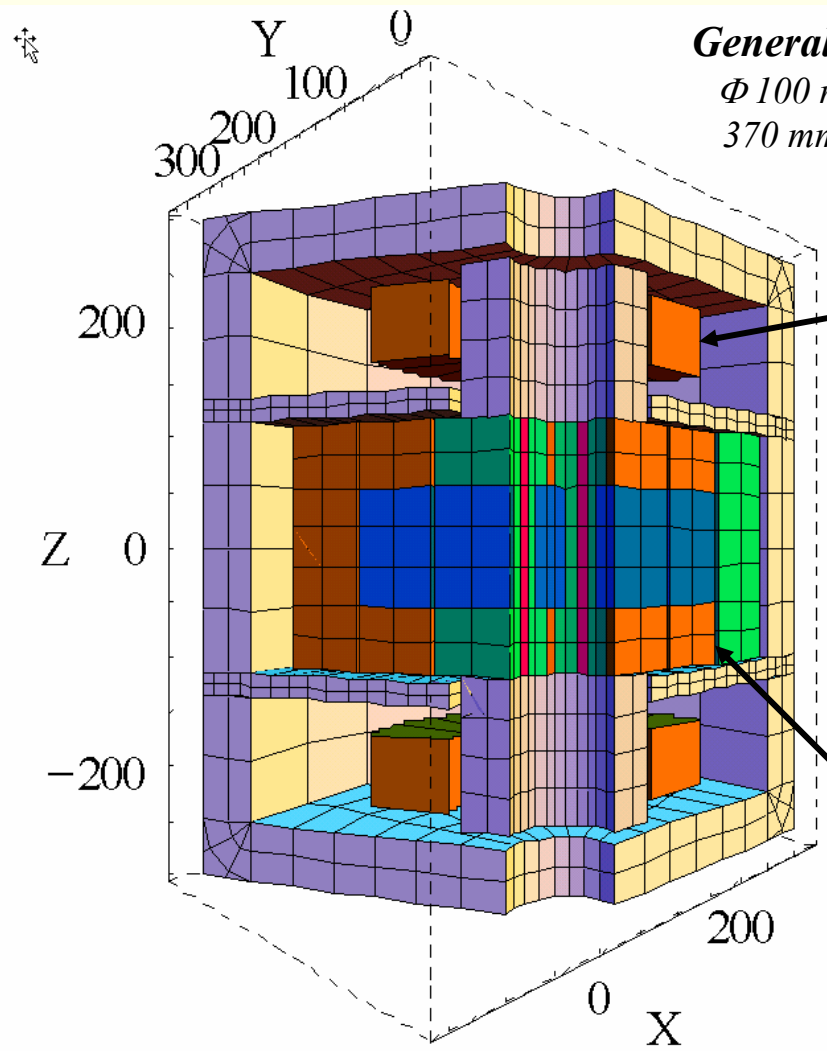
Figure 4: Finished prototype coil



Etudiées par Pantechnik sous contrat
Pantechnik / NSC (New Dehli) / Space Cryomagnetics

A-PHOENIX : 2T / 18-40 GHz HTS source magnetic structure

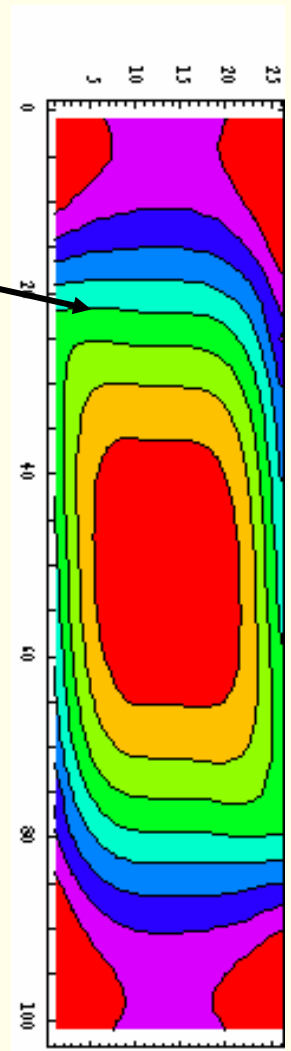
General magnetic structure
 Φ 100 mm (or less) hexapole
 370 mm axial mirror system



HTS coil

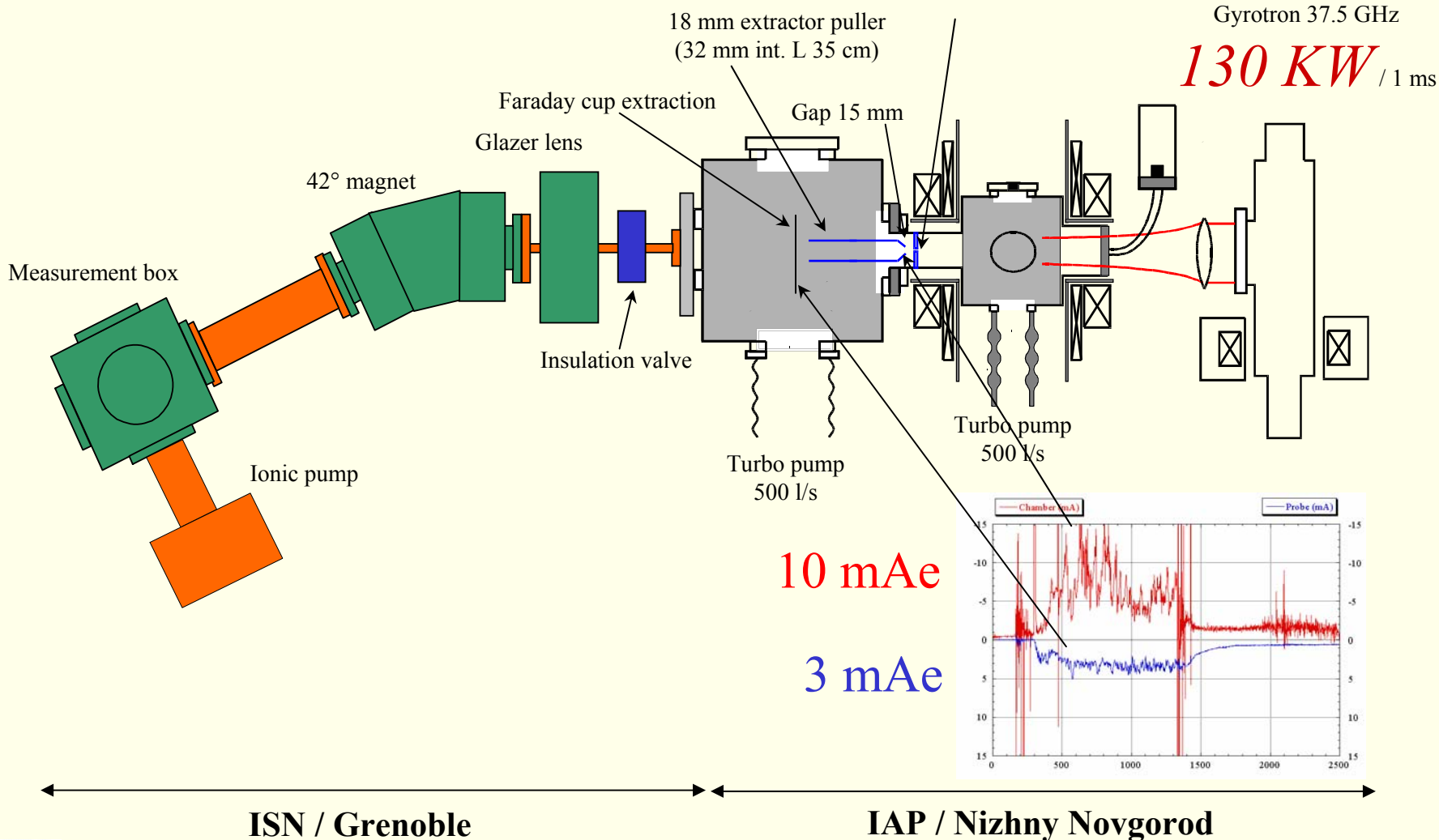
*3 slices hexapole
with fitted magnet*

*2T
|B| lines*

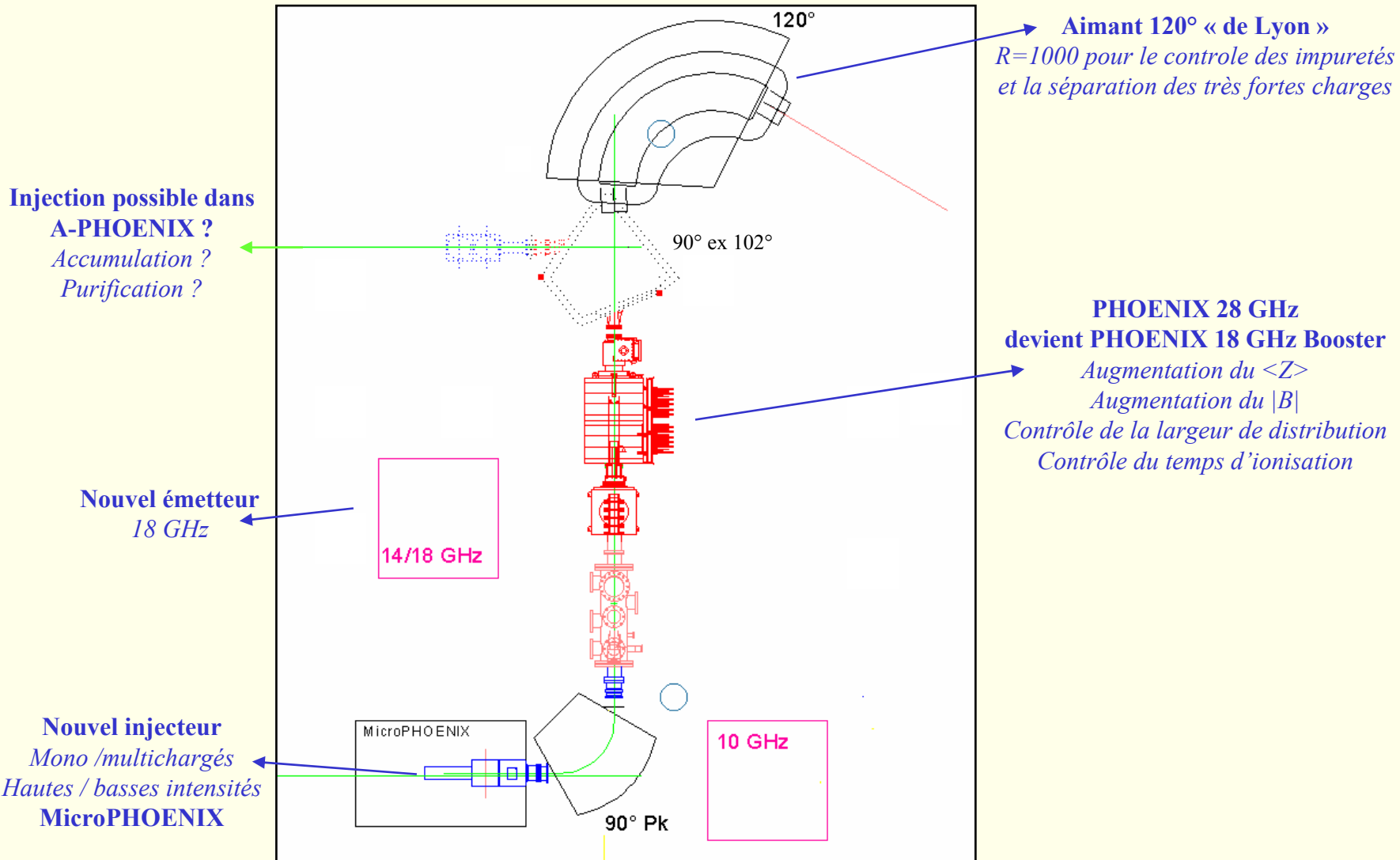


S_{imple} M_{irror} L_{on} S_{ource} 37 GHz

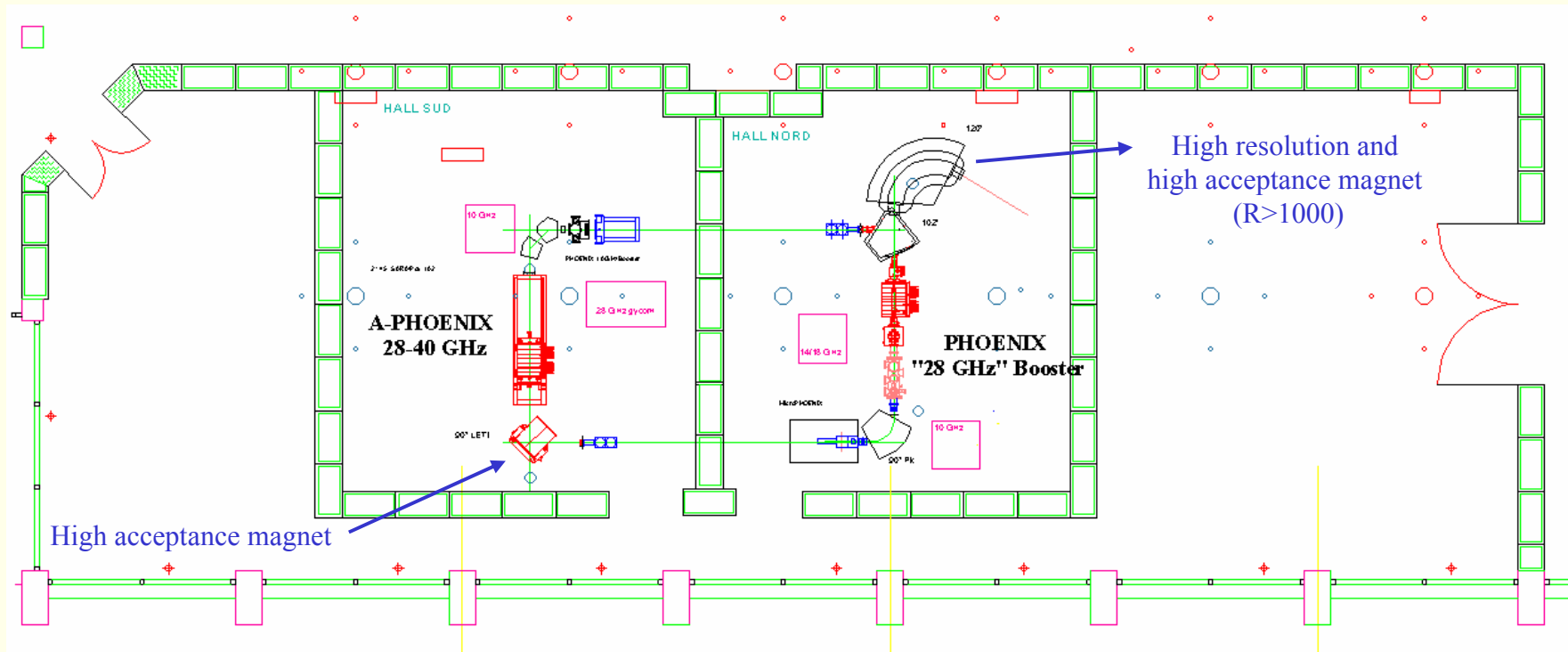
Ø 1 mm extraction hole
and no hexapole



Upgrading of the charge breeding system



Test benches at the new ISN/SSI laboratory : new sources and new beam lines
An open laboratory with 4 beam lines for ion source development



SSI "ring" : 4 beam lines with possible retro-injection system

*for the study of the generalisation of the charge breeding / retro injection process on any ECR sources
(metallic ion production, multicharged ion accumulation, very high charge state ion production)*